Notification about the transfer of the semiconductor business

The semiconductor business of Panasonic Corporation was transferred on September 1, 2020 to Nuvoton Technology Corporation (hereinafter referred to as "Nuvoton"). Accordingly, Panasonic Semiconductor Solutions Co., Ltd. became under the umbrella of the Nuvoton Group, with the new name of Nuvoton Technology Corporation Japan (hereinafter referred to as "NTCJ").

In accordance with this transfer, semiconductor products will be handled as NTCJ-made products after September 1, 2020. However, such products will be continuously sold through Panasonic Corporation.

Publisher of this Document is NTCJ.

If you would find description "Panasonic" or "Panasonic semiconductor solutions", please replace it with NTCJ.

Except below description page
 "Request for your special attention and precautions in using the technical information and semiconductors described in this book"

Nuvoton Technology Corporation Japan

Doc No. TT4-EA-14512

Revision. 2

Panasonic

MOS FET

FC6B21100L

FC6B21100L

Gate resistor installed Dual N-channel MOS FET

For lithium-ion secondary battery protection circuits

■ Features

- Low source-source ON resistance:Rss(on) typ. = 4.5 mΩ(VGS = 4.5 V)
- · CSP package:smallest & thinnest size
- · RoHS compliant (EU RoHS / MSL:Level 1 compliant)
- Marking Symbol: 33

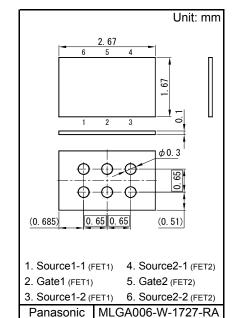
■ Packaging

Embossed type (Thermo-compression sealing): 10 000 pcs / reel (standard)

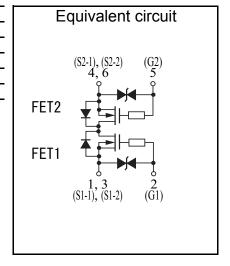
■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Source-source Voltage	VSS	12	V
Gate-source Voltage	VGS	±8	V
Source Current (DC) *1	IS	8	Α
Source Current (Pulsed) *1,*2	ISp	80	Α
Total Power Dissipation *1	PD	0.45	W
Channel Temperature	Tch	150	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Thermal resistance (ch-a)	Rth(ch-a)	278	°C/W

Note *1 Mounted on FR4 board ($25.4~\text{mm} \times 25.4~\text{mm} \times t1.0~\text{mm}$) using the minimum recommended pad size ($36\,\mu\text{m}$ Copper).



JEITA Code



^{*2} $t = 10 \mu s$, Duty Cycle $\leq 1 \%$

MOS FET

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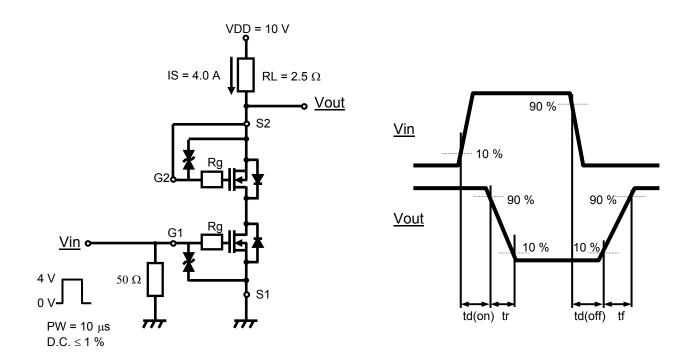
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■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Source-source Breakdown Voltage	VSSS	IS = 1 mA, VGS = 0 V	12			V
Zero Gate Voltage Source Current	ISSS	VSS = 12 V, VGS = 0 V			1.0	μΑ
Gate-source Leakage Current	IGSS	$VGS = \pm 8 \text{ V}, VSS = 0 \text{ V}$			±10	μА
	1000	$VGS = \pm 5 V$, $VSS = 0 V$			±1.0	
Gate-source Threshold Voltage	Vth	IS = 1.0 mA, VSS = 10 V	0.35	0.90	1.4	V
	RSS(on)1	,	3.4	4.5	5.7	
Source-source On-state Resistance		IS = 4.0 A, VGS = 3.8 V	3.6	4.9	6.3	mΩ
	RSS(on)3	IS = 4.0 A, VGS = 3.1 V	4	5.5	7.8	
	RSS(on)4	IS = 4.0 A, VGS = 2.5 V	4.2	6.5	11	
Body Diode Forward Voltage	VF(s-s)	IF = 8.0 A, VGS = 0 V		8.0	1.2	V
Input Capacitance *1	Ciss			4360		
Output Capacitance *1	Coss	VSS = 10 V, VGS = 0 V, f = 1 MHz		720		pF
Reverse Transfer Capacitance *1	Crss			670		
Turn-on delay Time *1,*2	td(on)	VDD = 10 V, VGS = 0 to 4.0 V		2.2		0
Rise Time *1,*2	tr	IS = 4.0 A		5.3		μS
Turn-off delay Time *1,*2	td(off)	VDD = 10 V, VGS = 4.0 to 0 V		13.9		0
Fall Time *1,*2	tf	IS = 4.0 A		12.1		μS
Total Gate Charge *1	Qg	VDD = 10 V		42		
Gate-source Charge *1	Qgs	VGS = 0 to 4.0 V,		14		nC
Gate-drain Charge *1	Qgd	IS = 8.0 A		13		

Note Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

^{*2} Measurement circuit for Turn-on Delay Time / Rise Time / Turn-off Delay Time / Fall Time



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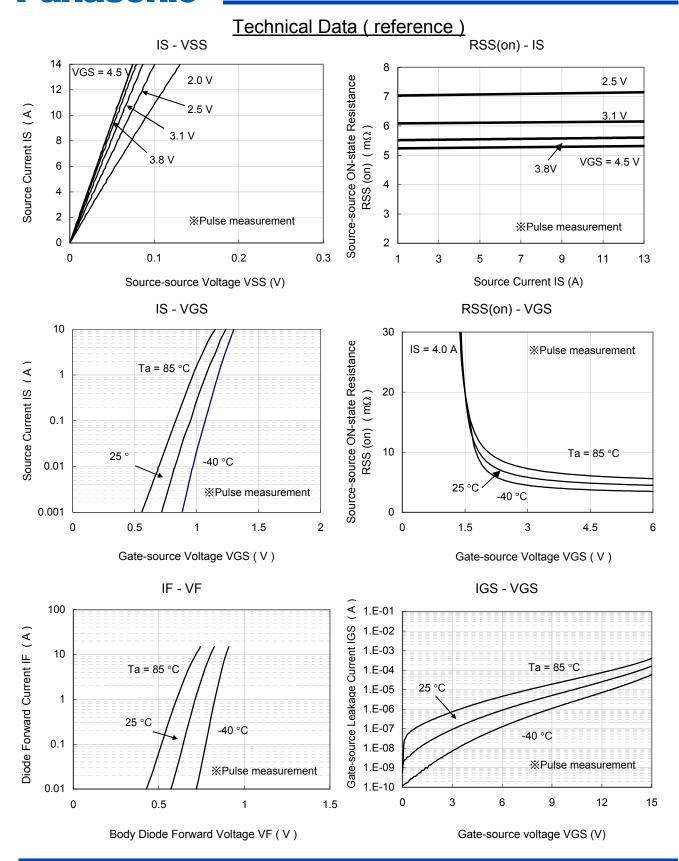
Established: 2013-01-28 Revised: 2013-02-22

^{*1} Assured by design

Panasonic

MOS FET

FC6B21100L



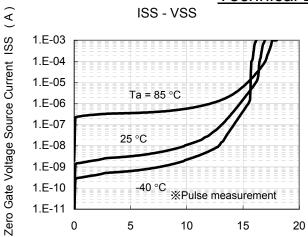
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Technical Data (reference)



Source-source Voltage VSS (V)

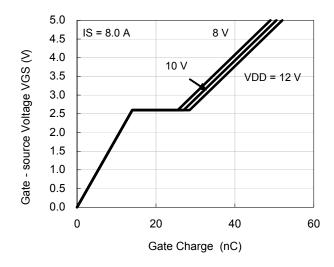
Destruction Current

Parameter	Conditions	Result	
Operation Test *1	VGS = 3.8 V, IS = 40 A,	PASS	
	t = 3 ms		
	VGS = 3.8 V, IS = 15 A,	PASS	
	t = 11 ms		
Destruction Current *1	VGS = 3.8 V,	90 A	
	t = 300 μs		
	VGS = 3.8 V,	72 A	
	t = 10 ms		
	VGS = 3.8 V,	59 A	
	t = 20 ms	0071	
	VGS = 3.8 V,	47 A	
	t = 50 ms		
	VGS = 3.8 V,	42 A	
	t = 100 ms		
	VGS = 3.8 V,	35 A	
	t = 200 ms	33 A	

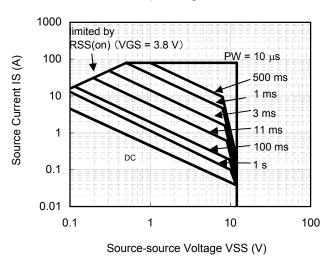
Ta = 25 °C,

Mounted on FR4 board ($25.4~mm \times 25.4~mm \times t1.0~r$ using the minimum recommended pad size (36 μm Copper).

Dynamic Input/Output Characteristics



Safe Operating Area



Ta = 25 °C,

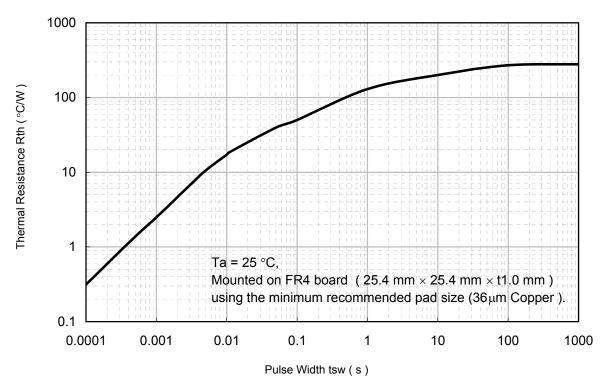
Mounted on FR4 board ($25.4~mm \times 25.4~mm \times t1.0~mm$) using the minimum recommended pad size (36 μm Copper).

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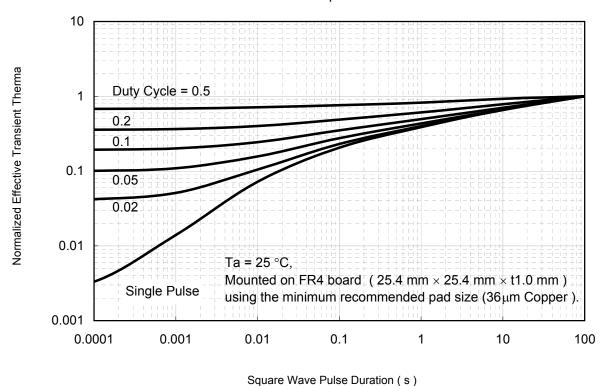
MOS FET

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Technical Data (reference) Rth - tsw



Thermal Response



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Established: 2013-01-28 Revised : 2013-02-22

Revision. 2

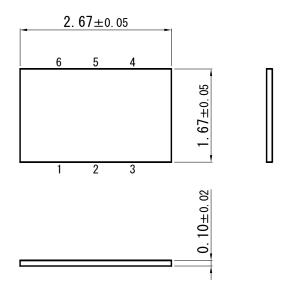
Panasonic

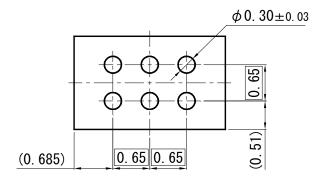
MOS FET

FC6B21100L

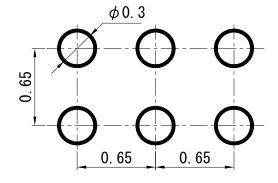
MLGA006-W-1727-RA

Unit: mm





■ Land Pattern (Reference) (Unit: mm)



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